Supplementary Materials:

Fabrication dual-functional electrodes of oxygen vacancy abundant NiCo₂O₄ nanosheets for advanced hybrid supercapacitors and Zn-ion

batteries

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Preparation of Co₃O₄ nanosheets

The electrodes of Co₃O₄ and ZnCo₂O₄ are synthesized using a similar method. For the preparation the Co₃O₄ on Ni foam, the used 2.5 mmol Co(NO₃)₂·6H₂O, 5 mmol of NH₄F and 12.5 mmol C₆H₁₂N₄ were dissolved in a mixed solution of 30 mL of H₂O stirring for 30 min. After that, the mixed solution was sealed and kept at 120 °C for 5 h. The Co₃O₄ nanowires were obtained by calcination of the Co precursor at 350 °C for 2 h at a rate of 2 °C·min⁻¹.

Preparation of ZnCo₂O₄ nanosheets

For the synthesis of ZnCo₂O₄ on Ni foam, the used 1 mmol Zn(NO₃)₂·6H₂O, 5 mmol Co(NO₃)₂·6H₂O, 2 mmol of NH₄F and 5 mmol C₆H₁₂N₄ were dissolved in a mixed solution of 40 mL of H₂O stirring for 30 min. After that, the mixed solution was sealed and kept at 120 °C for 5 h. The ZnCo₂O₄ nanowires were obtained by calcination of the Zn-Co precursor at 400 °C for 2 hours at a rate of 2 °C·min⁻¹.



Figure S1 (a, b) SEM image of the NiCo₂O₄ samples.



Figure S2 (a, b) SEM image of the V-NiCo₂O₄-3 samples.



Figure S3 (a, b) SEM image of the V-NiCo₂O₄-5 samples.



Figure S4 TEM images and (d) high-resolution TEM image of NiCo₂O₄.

Peak identity	2P _{1/2}	2P _{1/2}	2P _{3/2}	2P _{3/2}	2P _{1/2}	2P _{1/2}	2P _{3/2}	2P _{3/2}	0	0	0
Materials	Co ²⁺	C0 ³⁺	C0 ²⁺	C0 ³⁺	Ni ²⁺	Ni ³⁺	Ni ²⁺	Ni ³⁺	Ι	п	Ш
NiCo ₂ O ₄	0.48	0.52	0.53	0.47	0.43	0.57	0.60	0.40	0.26	0.37	0.42
V-NiCo ₂ O ₄ -4	0.63	0.37	0.68	0.32	0.52	0.48	0.63	0.37	0.32	0.55	0.13

Table S1 XPS peak area ratios of NiCo₂O₄ and V-NiCo₂O₄-4.



Figure S5 (a) UV-vis absorbance spectra of $NiCo_2O_4$ and V- $NiCo_2O_4$ -4 samples; (c) The experimental bandgaps of $NiCo_2O_4$ and V- $NiCo_2O_4$ -4 samples.



Figure S6 The atomic structure of $NiCo_2O_4$ (a) and V-NiCo_2O_4-4 (b); Minority spin channel in $NiCo_2O_4$ (c) and V-NiCo_2O_4-4 (d).



Figure S7 (a, b) electrons density image of $NiCo_2O_4$ and V- $NiCo_2O_4$ -4; (c, d) electron density difference of $NiCo_2O_4$ and V- $NiCo_2O_4$ -4.



Figure S8 (a, c, e) CV curves of NiCo₂O₄, V-NiCo₂O₄-3, V-NiCo₂O₄-5 electrodes at different scan rates; (b, d, f) GCD curves of the NiCo₂O₄, V-NiCo₂O₄-3, V-NiCo₂O₄-5 electrodes at different specific currents.



Figure S9 XRD patterns of Co₃O₄ and Co₃O₄-4.



Figure S10 XRD patterns of ZnCo₂O₄ and V-ZnCo₂O₄-4.







Figure S12 EPR spectra of ZnCo₂O₄ and V-ZnCo₂O₄-4.



ure S13 (a) CV curves of Co_3O_4 and Co_3O_4 -4 at the scan rate of 10 mV·s⁻¹; (b) Specific discharge capacitance at different current densities of Co_3O_4 and Co_3O_4 -4 h.



Figure S14 (a) CV curves of ZnCo₂O₄ and V-ZnCo₂O₄-4 at the scan rate of 10 mV·s⁻¹; (b) Specific discharge capacitance at different current densities of ZnCo₂O₄ and V-ZnCo₂O₄-4.



Figure S15 (a) CV curves of AC; (b) GCD curves of AC; (c) EIS curve of AC.



Figure S16 (a) GCD curves of the V-NiCo₂O₄ -4//AC HSC device at different voltages (from 1.5 to 1.8 V) at a specific current of 30 mA·cm⁻²; (b) EIS curves of the asassembled V-NiCo₂O₄-4//AC HSC device.

Material	Electrolyte	Performance	Cycling stability of Device	Sr.	
	v		v o v	No	
L-CuCo ₂ O ₄	3 M KOH	$139.72 \text{mAh} \cdot \text{g}^{-1}$ at 1 A · g^{-1}	85.5% after 10000 cycles	1	
150-N:ZnCo ₂ O ₄	3 М КОН	422.73 mAh·g ⁻¹ at 5 A·g ⁻¹	95.4% after 3000 cycles	2	
OV-MgCo ₂ O ₄	3 М КОН	54.11 mAh·g ⁻¹ at 1 A·g ⁻¹	82% after 10000 cycles	3	
OV-ZnCo ₂ O ₄	6 M KOH	293.14 mAh·g ⁻¹ at 1 A·g ⁻¹	No cycling	4	
ZnMoO ₄ -OV	6 M KOH	209.12 mAh·g ⁻¹ at 1.4 A·g ⁻¹	87.4% after 10000 cycles	5	
P-NiMoO ₄	1 M KOH	142.88 mAh·g ⁻¹ at 1.4 A·g ⁻¹	98.7% after 5000 cycles	6	
N-Bi ₂ MoO ₆	6 M KOH	$155.13 \text{ mAh} \cdot \text{g}^{-1}$ at 0.5 A $\cdot \text{g}^{-1}$	79% after 10000 cycles	7	
Ov-NiMn-LDH	2 M KOH	$32.8.6 \text{ mAh} \cdot \text{g}^{-1}$ at 1 A $\cdot \text{g}^{-1}$	No cycling	8	
Co ₃ O ₄ @Co/NC- HN	3 M KOH	273.9 mAh·g ⁻¹ at $1 \text{ A} \cdot \text{g}^{-1}$	92.6% after 4000 cycles	9	
v-Co ₃ O ₄ /CC	2 M LiOH	51.75 mAh·g ⁻¹ at 1 A·g^{-1}	81.4% after 5000 cycles	10	
N-GNTs@OV- Bi2O3	6 M KOH	196.47 mAh·g ⁻¹ at 1 A·g ⁻¹	85% after 10000 cycles	11	
Vo-NiCo LDH	6 M KOH	217.1 mAh·g ⁻¹ at 1 A·g^{-1}	75% after 10000 cycles	12	
MoO _{3-x}	1 M H ₂ SO ₄	273.33 mAh·g ⁻¹ at 5 A·g ⁻¹	75% after 10000 cycles	13	
Pd-Co ₃ O ₄	6 M KOH	$181.92 \text{ mAh} \cdot \text{g}^{-1}$ at 2 .06 A $\cdot \text{g}^{-1}$	92.5% after 4000 cycles	14	
L-CoFe ₂ O ₄ /C	2 M KOH	66.67 mAh·g ⁻¹ at 1 A·g^{-1}	No cycling	15	
Ov-MnO ₂ @ MnO ₂	1 M Na ₂ SO ₄	$125.67 \text{ mAh} \cdot \text{g}^{-1}$ at 1 A · g^{-1}	82% after10000 cycles	16	
α -MnO ₂	1 M KOH	$204.53 \text{ mAh} \cdot \text{g}^{-1}$ at 1 A $\cdot \text{g}^{-1}$	80.6% after10000 cycles	17	
LOV-MnO ₂	1 M Na ₂ SO ₄	$126.42 \text{ mAh} \cdot \text{g}^{-1}$	92.2% after10000 cycles	18	
V-NiCo ₂ O ₄ -4	2 M KOH	751.67 mAh·g ⁻¹ at 1 A·g ⁻¹	91.9% after 10000 cycles	This work	

 Table S2. Comparison of the similar device properties of the oxygen-deficient metal oxide as cathode



Figure S17 EIS curves of the as-assembled V-NiCo₂O₄-4//Zn batteries.

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